

**4A, 1200V Ultrafast Diodes**

The RURD4120S9A\_F085 are ultrafast diodes with soft recovery characteristics ( $t_{rr} < 70ns$ ). They have low forward voltage drop and are silicon nitride passivated ion-implanted epitaxial planar construction.

These devices are intended for use as freewheeling/clamping diodes and rectifiers in a variety of switching power supplies and other power switching applications. Their low stored charge and ultrafast soft recovery minimize ringing and electrical noise in many power switching circuits reducing power loss in the switching transistors.

Formerly developmental type TA49036.

**Ordering Information**

PART NUMBER	PACKAGE	BRAND
RURD4120S9A_F085	TO-252	UR4120

**Symbol**



**Features**

- Ultrafast with Soft Recovery . . . . . <70ns
- Operating Temperature . . . . . 175°C
- Reverse Voltage . . . . . 1200V
- Avalanche Energy Rated
- Planar Construction
- Qualified to ACE Q101
- RoHS Compliant

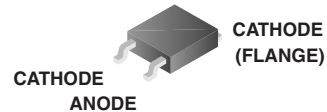


**Applications**

- Switching Power Supplies
- Power Switching Circuits
- General Purpose

**Packaging**

**JEDEC STYLE TO-252**



**Absolute Maximum Ratings**  $T_C = 25^{\circ}C$ , Unless Otherwise Specified

	RURD4120S9A_F085	UNITS
Peak Repetitive Reverse Voltage . . . . . $V_{RRM}$	1200	V
Working Peak Reverse Voltage . . . . . $V_{RWM}$	1200	V
DC Blocking Voltage . . . . . $V_R$	1200	V
Average Rectified Forward Current . . . . . $I_{F(AV)}$ ( $T_C = 152^{\circ}C$ )	4	A
Repetitive Peak Surge Current . . . . . $I_{FRM}$ (Square Wave, 20kHz)	8	A
Nonrepetitive Peak Surge Current . . . . . $I_{FSM}$ (Halfwave, 1 Phase, 60Hz)	40	A
Maximum Power Dissipation . . . . . $P_D$	50	W
Avalanche Energy (See Figures 10 and 11) . . . . . $E_{AVL}$	10	mJ
Operating and Storage Temperature . . . . . $T_{STG}, T_J$	-65 to 175	°C

**Electrical Specifications**  $T_C = 25^\circ\text{C}$ , Unless Otherwise Specified

SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNITS
$V_F$	$I_F = 4\text{A}$	-	-	2.1	V
	$I_F = 4\text{A}, T_C = 150^\circ\text{C}$	-	-	1.9	V
$I_R$	$V_R = 1200\text{V}$	-	-	100	$\mu\text{A}$
	$V_R = 1200\text{V}, T_C = 150^\circ\text{C}$	-	-	500	$\mu\text{A}$
$t_{rr}$	$I_F = 1\text{A}, dI_F/dt = 200\text{A}/\mu\text{s}$	-	-	70	ns
	$I_F = 4\text{A}, dI_F/dt = 200\text{A}/\mu\text{s}$	-	-	90	ns
$t_a$	$I_F = 4\text{A}, dI_F/dt = 200\text{A}/\mu\text{s}$	-	40	-	ns
$t_b$	$I_F = 4\text{A}, dI_F/dt = 200\text{A}/\mu\text{s}$	-	28	-	ns
$Q_{RR}$	$I_F = 4\text{A}, dI_F/dt = 200\text{A}/\mu\text{s}$	-	335	-	nC
$C_J$	$V_R = 10\text{V}, I_F = 0\text{A}$	-	15	-	pF
$R_{\theta JC}$		-	-	3	$^\circ\text{C}/\text{W}$

**DEFINITIONS**

$V_F$  = Instantaneous forward voltage (pw = 300 $\mu\text{s}$ , D = 2%).

$I_R$  = Instantaneous reverse current.

$t_{rr}$  = Reverse recovery time (See Figure 9), summation of  $t_a + t_b$ .

$t_a$  = Time to reach peak reverse current (See Figure 9).

$t_b$  = Time from peak  $I_{RM}$  to projected zero crossing of  $I_{RM}$  based on a straight line from peak  $I_{RM}$  through 25% of  $I_{RM}$  (See Figure 9).

$Q_{RR}$  = Reverse recovery time.

$C_J$  = Junction capacitance.

$R_{\theta JC}$  = Thermal resistance junction to case.

pw = Pulse width.

D = Duty cycle.

**Typical Performance Curves**

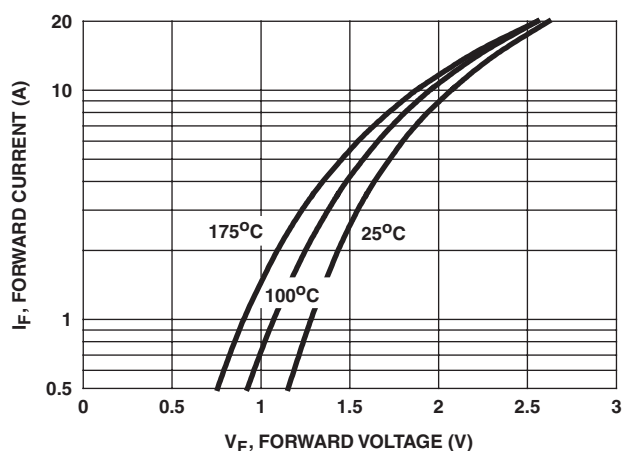


FIGURE 1. FORWARD CURRENT vs FORWARD VOLTAGE

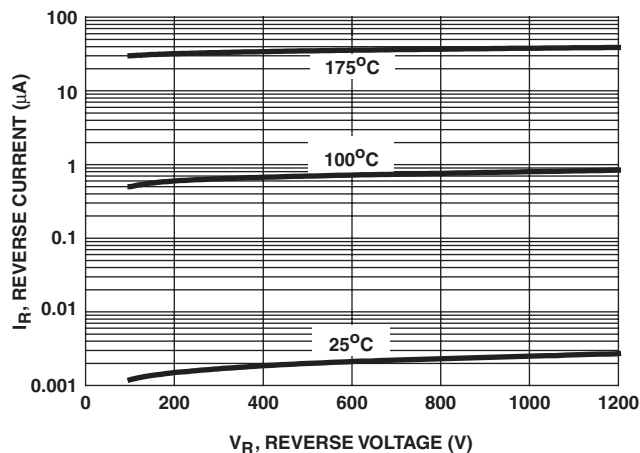


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE

Typical Performance Curves (Continued)

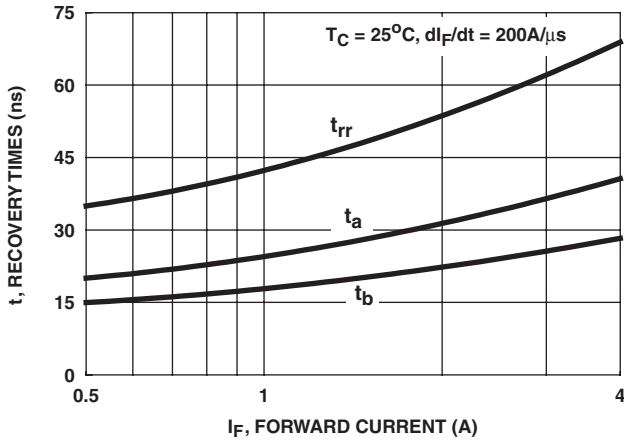


FIGURE 3.  $t_{rr}$ ,  $t_a$  AND  $t_b$  CURVES vs FORWARD CURRENT

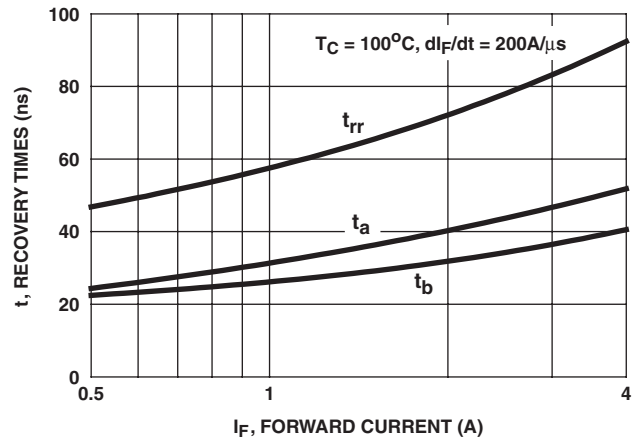


FIGURE 4.  $t_{rr}$ ,  $t_a$  AND  $t_b$  CURVES vs FORWARD CURRENT

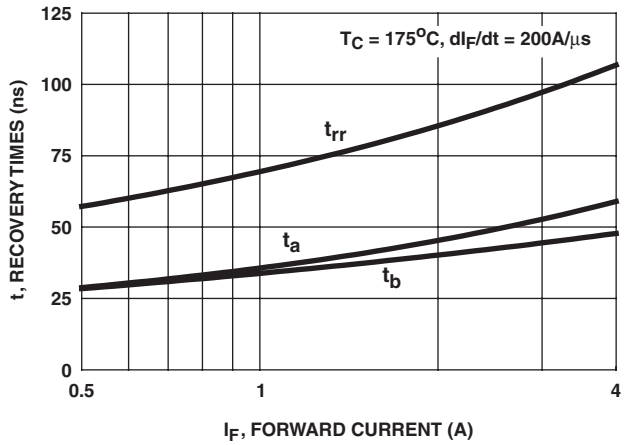


FIGURE 5.  $t_{rr}$ ,  $t_a$  AND  $t_b$  CURVES vs FORWARD CURRENT

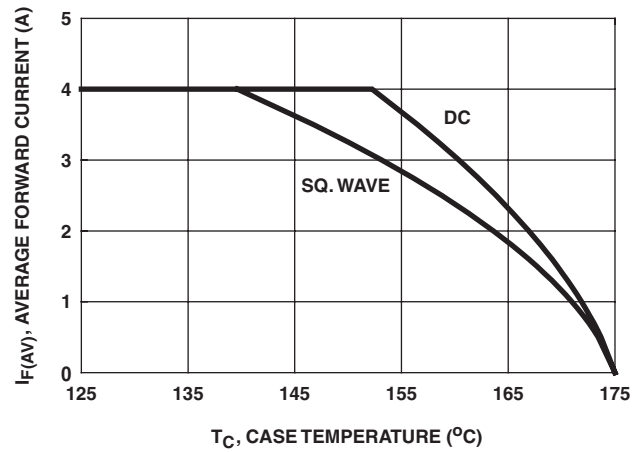


FIGURE 6. CURRENT DERATING CURVE

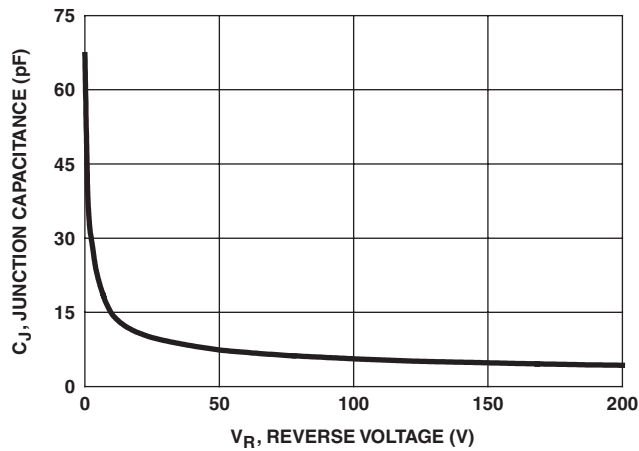


FIGURE 7. JUNCTION CAPACITANCE vs REVERSE VOLTAGE

Test Circuits and Waveforms

$V_{GE}$  AMPLITUDE AND  
 $R_G$  CONTROL  $di_F/dt$   
 $t_1$  AND  $t_2$  CONTROL  $I_F$

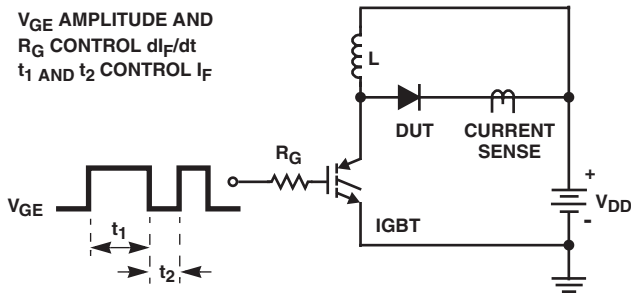


FIGURE 8.  $t_{rr}$  TEST CIRCUIT

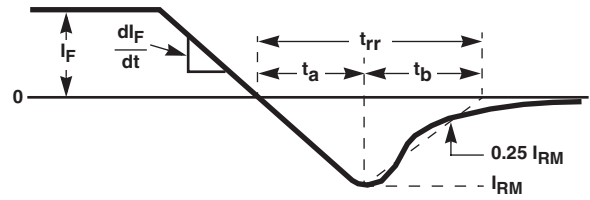


FIGURE 9.  $t_{rr}$  WAVEFORMS AND DEFINITIONS

$I = 1A$   
 $L = 20mH$   
 $R < 0.1\Omega$   
 $E_{AVL} = 1/2LI^2 [V_{R(AVL)}/(V_{R(AVL)} - V_{DD})]$   
 $Q_1 = IGBT (BV_{CES} > DUT V_{R(AVL)})$

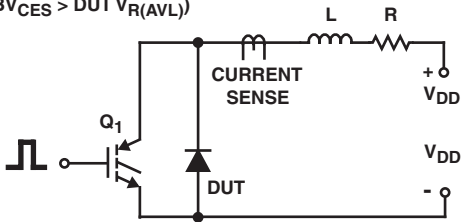


FIGURE 10. AVALANCHE ENERGY TEST CIRCUIT

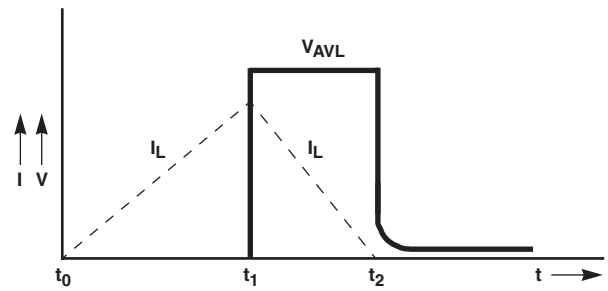








FIGURE 11. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS



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